

ZLM3019AH规格书 V1. 0

N-Channel Trench Power MOSFET

ZLW-QW-EN-G147



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Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
30V	3Ω@10V	100mA
	4Ω@4.5V	

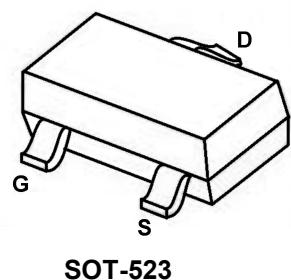
Feature

- Low on-resistance
- Fast switching speed
- Low voltage drive makes this device ideal for Portable equipment
- Easily designed drive circuits
- Easy to parallel

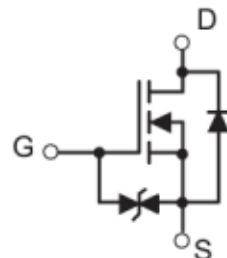
Application

- Interfacing , Switching

Package:



Circuit diagram



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	100	mA
Power Dissipation	P _D	0.15	W
Thermal Resistance from Junction to Ambient	R _{θJA}	833	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55~ +150	°C

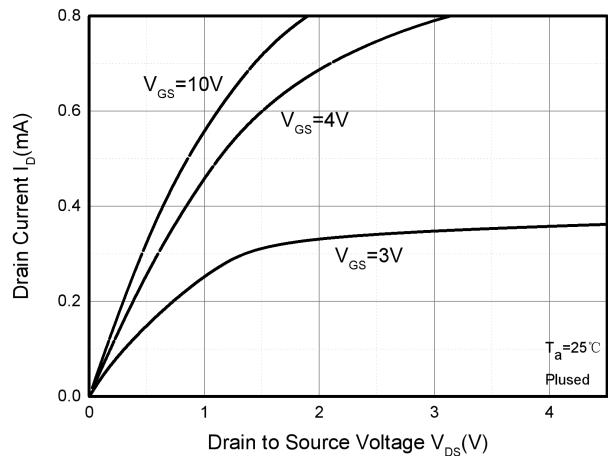
Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = 48V, V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±5	μA
Gate threshold voltage ¹⁾	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	0.8	1	1.45	V
Drain-source on-resistance ¹⁾	R _{DS(on)}	V _{GS} = 10V, I _D = 500mA		1.5	3	Ω
		V _{GS} = 4.5V, I _D = 200mA		1.8	4	
Dynamic characteristics²⁾						
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHz		27		pF
Output Capacitance	C _{oss}			13		
Reverse Transfer Capacitance	C _{rss}			6		
Switching Characteristics¹⁾²⁾						
Turn-on delay time	t _{d(on)}	V _{DD} =30V, I _D =0.29A, V _{GS} =10V, R _G =6Ω			5	nS
Rise time	tr				18	
Turn-off delay time	t _{d(off)}				36	
Fall time	tf				14	
Source-Drain Diode characteristics						
Diode Forward voltage	V _{SD}	V _{GS} = 0V, I _S = 500mA	0.5		1.4	V

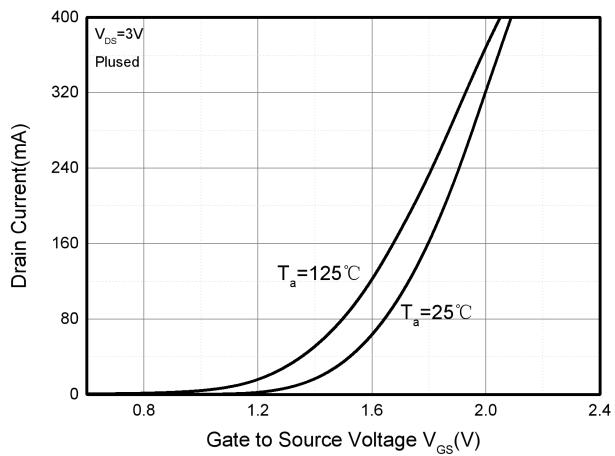
Notes:

- 1) Pulse Test: Pulse Width ≤300μs, Duty Cycle ≤2%.
- 2) These parameters have no way to verify.

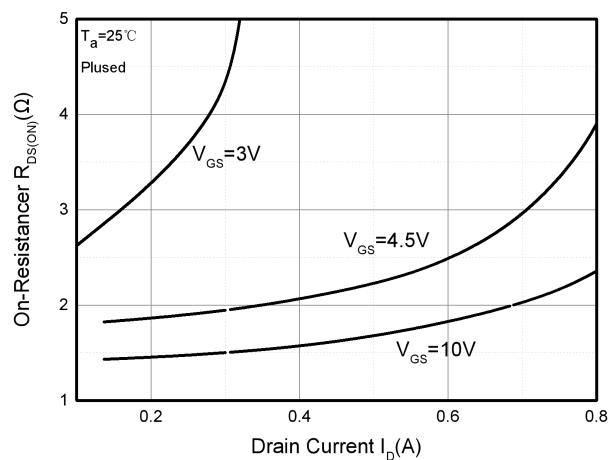
Typical Characteristics



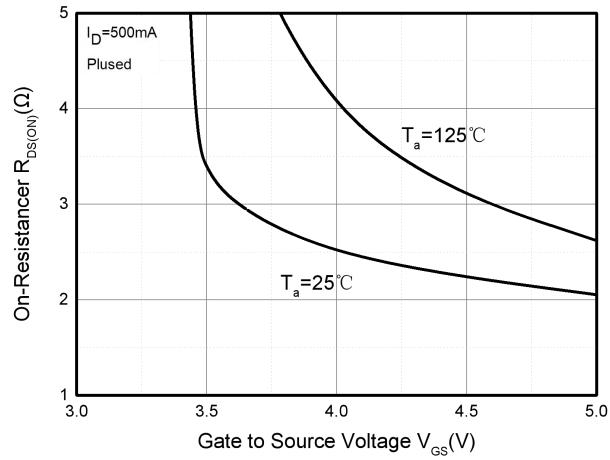
Output Characteristics



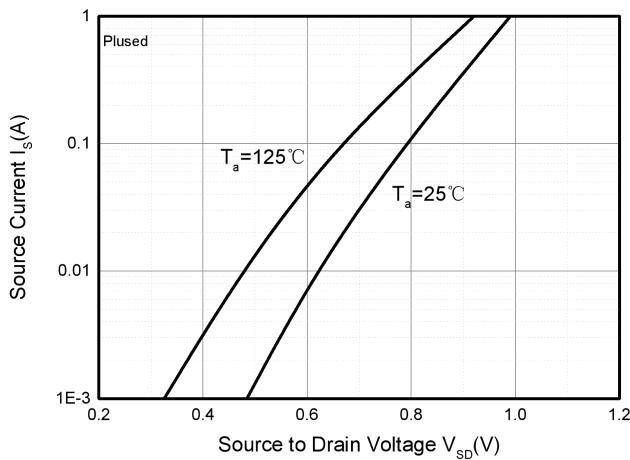
Transfer Characteristics



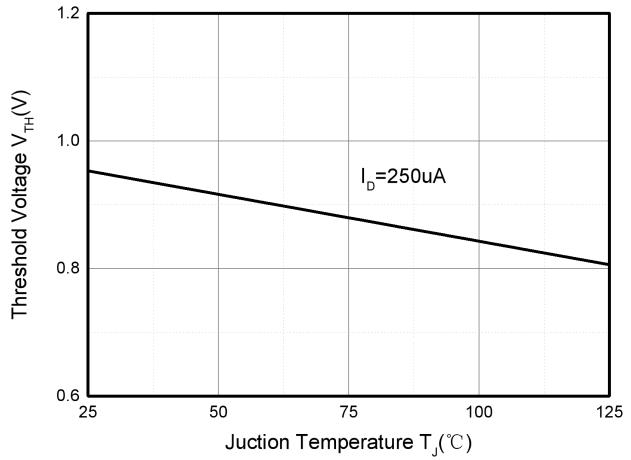
RDS(ON)——ID



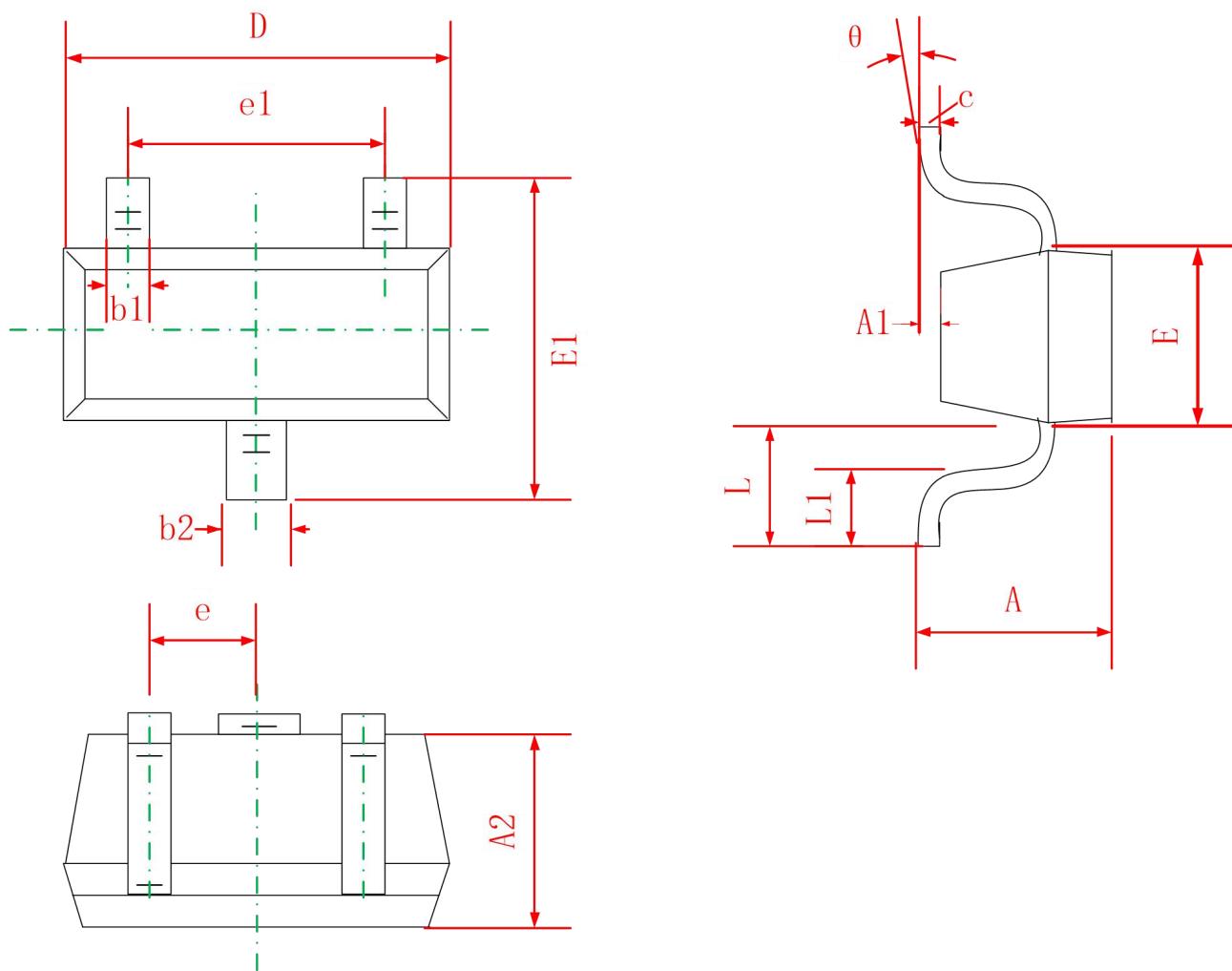
RDS(ON)——VGS



IS——VSD



Threshold Voltage

SOT-523 Package Information


Symbol	Dimensions In Millimeters	
	Min	Max
A	0.700	0.900
A1	0.000	0.100
A2	0.700	0.800
b1	0.150	0.250
b2	0.250	0.350
C	0.100	0.200
D	1.500	1.700
E	0.700	0.900
E1	1.450	1.750
e	0.500 TYP	
e1	0.900	1.100
L	0.400 REF	
L1	0.260	0.460
θ	0°	8°